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Last five years publication list

- 1. Issues and Challenges of Rechargeable Lithium Batteries, O Padmaraj, N Satyanarayana, SA Suthanthiraraj, C Venkateswaran, Rechargeable Lithium-Ion Batteries: Trends and Progress in Electric Vehicles, 38
- 2. Non-adiabatic small polaron hopping transport above metal-like to insulator transition in the vacant 3d-orbital Tb₂Ti₂O₇ pyrochlore oxide, BS Kumar, YN Kumar, V Kamalarasan, C Venkateswaran, Journal of Materials Science: Materials in Electronics, 1-11
- 3. Optical property and thermal stability studies on Cs₃Bi₂I₉ perovskite quantum dots for photovoltaic application, V Kamalarasan, BS Kumar, T Mukilraj, C Venkateswaran, AIP Conference Proceedings 2265 (1), 030168
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- 6. A study of hybrid bifunctional CuCo₂O₄/rGO electrocatalytic oxygen reduction and evolution reactions for rechargeable metal-air batteries, O Padmaraj, C Venkateswaran, AIP Conference Proceedings 2265 (1), 030677
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- 15. Structural properties, optical, electrical and magnetic behavior of bismuth doped Gd₃Fe₅O₁₂ prototype garnet, N Aparnadevi, KS Kumar, M Manikandan, BS Kumar, JS Punitha, C Venkateswaran, Journal of Materials Science: Materials in Electronics 31 (3), 2081-2088

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- 21. First Observed Metal to Insulator Transition in the vacant 3d orbital Quantum Spin Liquid TbTiO, BS Kumar, C Venkateswaran, arXiv preprint arXiv:1904.12478
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- 26. Exploration of photoanode characteristics of a mixed ferroelectric ZnSnO₃and semiconducting Zn₂SnO₄ phase for photovoltaic applications, M Manikandan, T Mukilraj, C Venkateswaran, SM Babu, Journal of Materials Science: Materials in Electronics 29 (17), 15106-15111
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